



SSDI
SOLID STATE DEVICES, INC.

14830 Valley View Blvd * La Mirada, Ca 90638
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Designer's Data Sheet

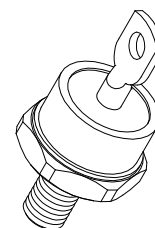
FEATURES:

- Ultra Fast Recovery: 60 nsec maximum.
- PIV to 1200 Volts.
- Low Forward Voltage Drop.
- Low Leakage Current.
- Hermetically Sealed.
- Single Chip Construction.
- For High Efficiency Applications.
- TX, TXV, and Space Level Screening Available

**SDR803
thru
SDR818**

**100 AMP
50 - 1200 VOLTS
60 nsec
ULTRA FAST RECTIFIER**

DO-5



Maximum Ratings		SYMBOL	VALUE	UNITS
Peak Repetitive Reverse and DC Blocking Voltage @ 100 μ A	SDR803	V _{RRM} V _{RWM} V _R	50	Volts
	SDR804		100	
	SDR805		150	
	SDR806		200	
	SDR807		250	
	SDR808		300	
	SDR809		350	
	SDR810		400	
	SDR811		500	
	SDR812		600	
	SDR813		700	
	SDR814		800	
	SDR815		900	
	SDR816		1000	
	SDR817		1100	
	SDR818		1200	
Average Rectified Forward Current (Resistive Load, 60Hz, Sine Wave, T _A = 25 °C)		I _O	100	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, T _A = 25°C)	SDR803 - 806	I _{FSM}	1000	Amps
	SDR807 - 809		800	
	SDR810 - 814		700	
	SDR815 - 818		600	
Operating and Storage Temperature		T _{OP} & T _{STG}	-55 TO +175	°C
Maximum Thermal Resistance Junction to Case		R _{θJC}	0.85	°C/W

NOTE: All specifications are subject to change without notification.
SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: RU0059F

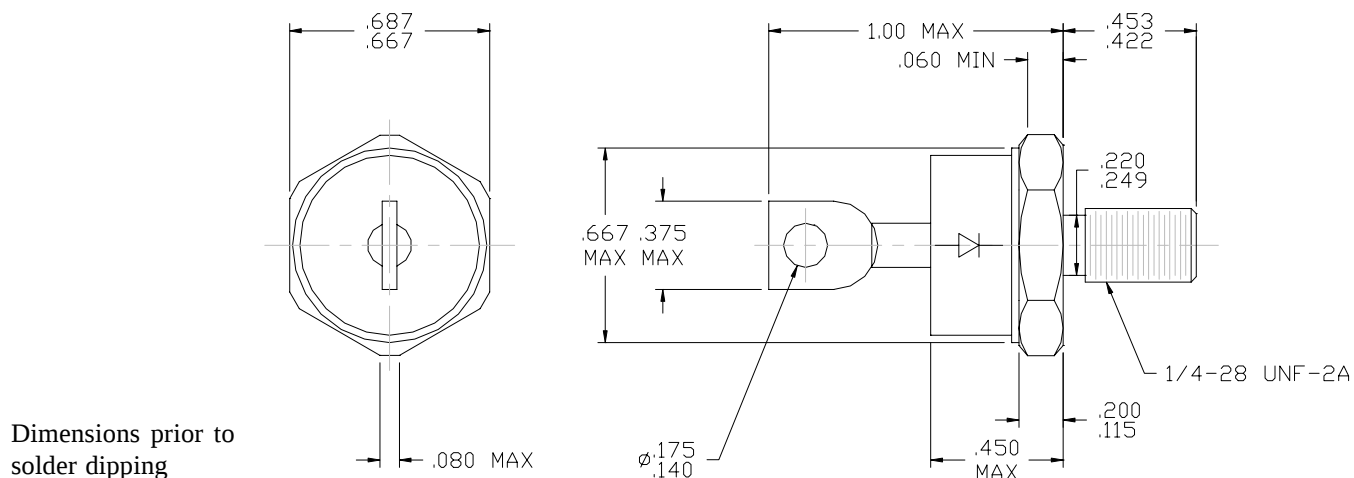
SDR803**thru**[查询"SDR803"供应商](#)**SDR818****SOLID STATE DEVICES, INC.**

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Electrical Characteristics		SYMBOL	MAXIMUM	UNITS
Instantaneous Forward Voltage Drop ($I_F = 100A_{DC}$, $T_A = 25^\circ C$, 300 - 500 μs Pulse)	SDR803 - 806	V_{F1}	1.00	V_{DC}
	SDR807 - 810		1.50	
	SDR811 - 814		1.85	
	SDR815 - 818		1.90	
Instantaneous Forward Voltage Drop ($I_F = 100A_{DC}$, $T_A = -55^\circ C$, 300 - 500 μs Pulse)	SDR803 - 806	V_{F2}	1.10	V_{DC}
	SDR807 - 810		1.60	
	SDR811 - 814		1.95	
	SDR815 - 818		2.00	
Reverse Leakage Current (Rated V_R , 300 μs minimum Pulse)	$T_A = 25^\circ C$	I_R	100	μA
	$T_A = 100^\circ C$		10	
Junction Capacitance ($V_R = 10 V_{DC}$, $T_A = 25^\circ C$, $f = 1 MHz$)		C_J	700	pF
Reverse Recovery Time ($I_F = 500 mA$, $I_R = 1 A$, $I_{RR} = 250 mA$, $T_A = 25^\circ C$)		t_{RR}	60	nsec

CASE OUTLINE: DO-5**TYPICAL OPERATING CURVES**(T_A = 25°C unless otherwise specified)